TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSVII)

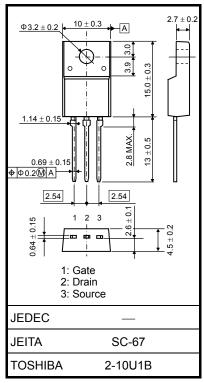
TK8A50DA

Switching Regulator Applications

- Low drain-source ON-resistance: RDS (ON) = 0.76 Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 4.1 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \ \mu A (max) (V_{DS} = 500 \ V)$
- Enhancement-mode: $V_{th} = 2.4$ to 4.4 V ($V_{DS} = 10$ V, $I_D = 1$ mA)

| Characteristics | | Symbol | Rating | Unit | |
|---|------------------------------|------------------|------------|------|--|
| Drain-source voltage | | V _{DSS} | 500 | V | |
| Gate-source voltage | | V _{GSS} | ±30 | V | |
| Drain current | DC (Note 1) | ۱ _D | 7.5 | | |
| | Pulse (t = 1 ms) (Note 1) | I _{DP} | 30 | A | |
| Drain power dissipati | on (Tc = 25°C) | PD | 35 | W | |
| Single pulse avalanche energy (Note 2) | | E _{AS} | 140 | mJ | |
| Avalanche current | | I _{AR} | 7.5 | А | |
| Repetitive avalanche energy (Note 3) | | E _{AR} | 3.5 | mJ | |
| Channel temperature | | T _{ch} | 150 | °C | |
| Storage temperature range | | T _{stg} | –55 to 150 | °C | |

Absolute Maximum Ratings (Ta = 25°C)



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

| Characteristics | Symbol | Max | Unit | |
|--|------------------------|------|------|--|
| Thermal resistance, channel to case | R _{th (ch-c)} | 3.57 | °C/W | |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 62.5 | °C/W | |

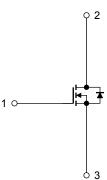
Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 4.2 mH, R_G = 25 Ω , I_{AR} = 7.5 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

Internal Connection



Unit: mm

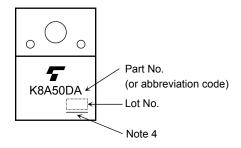
Electrical Characteristics (Ta = 25°C)

| Char | acteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|------------------------------|----------------|----------------------|---|-----|------|------|------|
| Gate leakage current | | I _{GSS} | $V_{GS}=\pm 30~V,~V_{DS}=0~V$ | _ | | ±1 | μA |
| Drain cut-off current | | I _{DSS} | $V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ | _ | | 10 | μA |
| Drain-source bre | akdown voltage | V (BR) DSS | $I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$ | 500 | | | V |
| Gate threshold ve | oltage | V _{th} | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$ | 2.4 | | 4.4 | V |
| Drain-source ON | -resistance | R _{DS (ON)} | $V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3.8 \text{ A}$ | _ | 0.76 | 1.04 | Ω |
| Forward transfer | admittance | Y _{fs} | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 3.8 \text{ A}$ | 1.0 | 4.1 | | S |
| Input capacitance | | C _{iss} | | _ | 700 | | pF |
| Reverse transfer capacitance | | C _{rss} | V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz | _ | 4 | | |
| Output capacitance | | C _{oss} | | | 80 | | |
| Switching time | Rise time | tr | $\begin{array}{c} 10 \text{ V} \\ \text{V}_{GS} \\ 0 \text{ V} \\ 50 \Omega \\ \end{array} \begin{array}{c} \text{I}_{D} = 3.8 \text{ A} \text{ V}_{OUT} \\ \text{V}_{GS} \\ \text{V}_{DD} \approx 200 \text{ V} \\ \text{V}_{DD} \approx 200 \text{ V} \\ \end{array}$ | | 20 | _ | - ns |
| | Turn-on time | t _{on} | | | 40 | | |
| | Fall time | t _f | | | 11 | | |
| | Turn-off time | t _{off} | | | 60 | | |
| Total gate charge | | Qg | | _ | 16 | _ | |
| Gate-source charge | | Q _{gs} | $V_{DD}\approx 400$ V, $V_{GS}=10$ V, $I_{D}=7.5$ A | | 10 | | nC |
| Gate-drain charge | | Q _{gd} | | _ | 6 | | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|---|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | — | _ | _ | 7.5 | А |
| Pulse drain reverse current (Note 1) | I _{DRP} | — | _ | | 30 | А |
| Forward voltage (diode) | V _{DSF} | I _{DR} = 7.5 A, V _{GS} = 0 V | _ | _ | -1.7 | V |
| Reverse recovery time | t _{rr} | $I_{DR} = 7.5 \text{ A}, V_{GS} = 0 \text{ V},$ | _ | 1200 | _ | ns |
| Reverse recovery charge | Q _{rr} | dl _{DR} /dt = 100 A/μμs | _ | 8.5 | _ | μC |

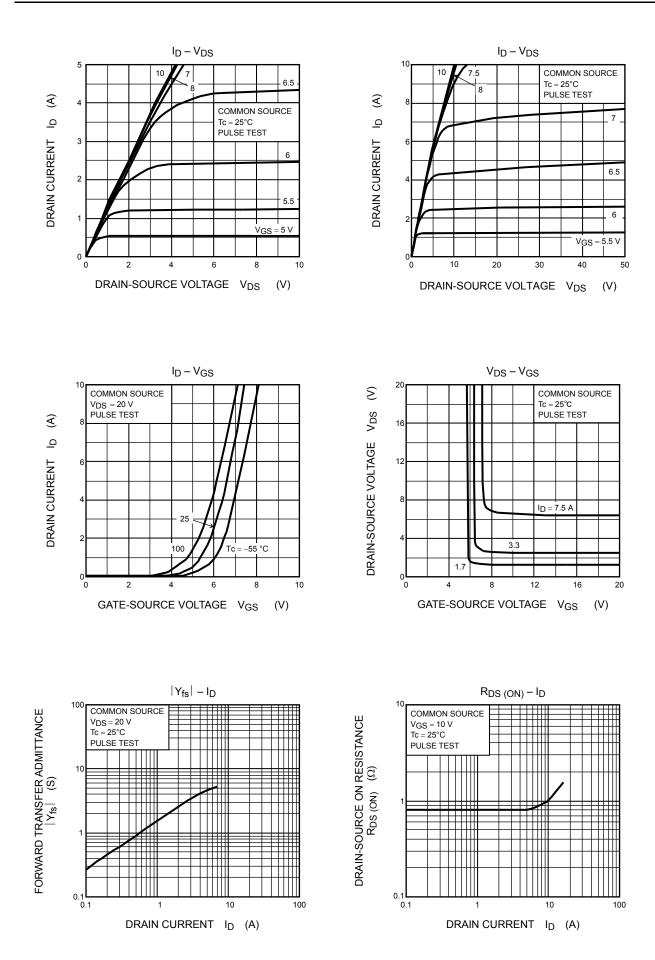
Marking



Note 4 : A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

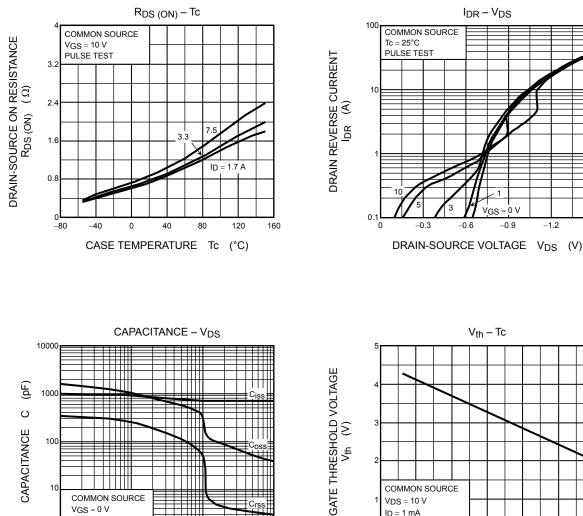
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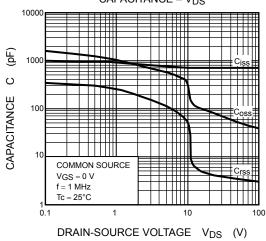


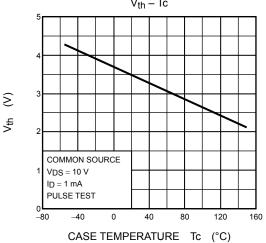
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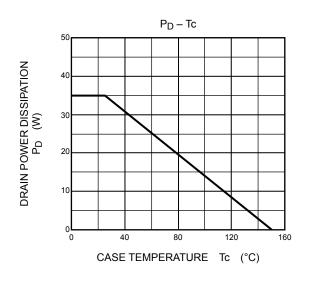
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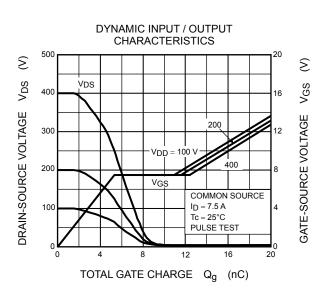
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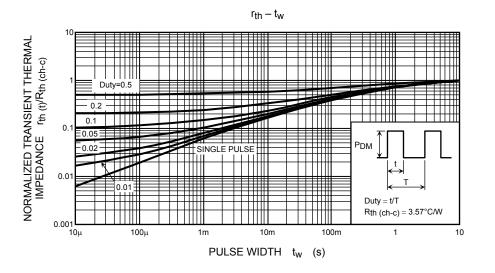




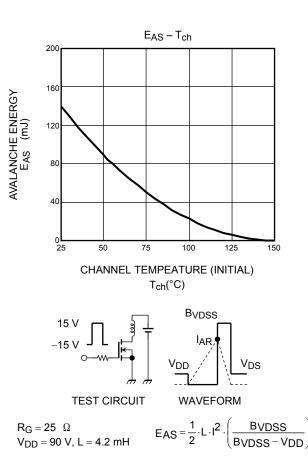








SAFE OPERATING AREA 100 (pulsed) ID max nax (continu 100 µs 10 E <u>_</u> DC operation Tc = 25°C DRAIN CURRENT 0.1 *: Single nonrepetitive pulse Tc = 25°C 0.01 Curves must be derated linearly with increase in temperature. VDSS max 0.001 0.1 1 10 100 1000 DRAIN-SOURCE VOLTAGE VDS (V)



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